NSN 5961-01-580-0968

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-580-0968 **Overall Length:** 2.90 millimeters **Overall Height:** 2.37 millimeters **Overall Width:** 1.01 millimeters **Function For Which Designed:** Avalanche diode **Features Provided:** High power **Semiconductor Material:** Silicon all semiconductor **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius junction and 125.0 degrees celsius junction **Product Name:** Low capacitance tvs diode array **Special Features:** Molding compound flammability rating = ul 94v-0 **Special Test Features:** Peak pulse power = 500 watts, peak pulse current = 25 amps, peak forward voltage = 1.5 volts Shelf Life: N/a **Unit Of Measure: Demilitarization:** No